# Witt, High Linearity InGaP HBT Amplifier

The Communications Edge <sup>TM</sup>

**Product Information** 

#### **Product Features**

- 800 1000 MHz
- +28.5 dBm P1dB
- +44 dBm Output IP3
- 18 dB Gain @ 900 MHz
- Single Positive Supply (+5V)
- Available in 16pin 4mm QFN package

#### **Applications**

- Final stage amplifiers for Repeaters
- Mobile Infrastructure

#### Specifications (1)

Parameter	Units	Min	Тур	Max
Operational Bandwidth	MHz	800		1000
Test Frequency	MHz		850	
Gain	dB		17	
Output P1dB	dBm		+28	
Output IP3 <sup>(2)</sup>	dBm		+44	
Test Frequency	MHz		900	
Gain	dB	15.5	17.8	
Input Return Loss	dB		18	
Output Return Loss	dB		7	
Output P1dB	dBm	+27	+28.7	
Output IP3 <sup>(2)</sup>	dBm	+42.5	+43	
IS-95A Channel Power @ -45 dBc ACPR, 1960 MHz	dBm		+23	
Noise Figure	dB		7	
Operating Current Range, Icc (3)	mA	200	250	300
Device Voltage, Vcc	V		+5	

1. Test conditions unless otherwise noted:  $25^{\circ}$ C, Vsupply = +5 V, in tuned application circuit.

2. 30IP measured with two tones at an output power of +11 dBm/tone separated by 1 MHz. The suppression on the largest IM3 product is used to calculate the 30IP using a 2:1 rule.

3. This corresponds to the quiescent current or operating current under small-signal conditions into pins 6, 7, and 8. It is expected that the current can increase by an additional 50 mA at P1dB. Pin 1 is used as a reference voltage for the internal biasing circuitry. It is expected that Pin 1 will pull 12mA of current when used with a series bias resistor of R1=100Ω. (ie. total device current typically will be 262 mA.)

#### **Absolute Maximum Rating**

Parameter	Rating
Operating Case Temperature	-40 to +85 °C
Storage Temperature	-65 to +150 °C
RF Input Power (continuous)	+22 dBm
Device Voltage	+8 V
Device Current	400 mA
Device Power	2 W
Junction Temperature	+250 °C

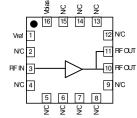
#### Operation of this device above any of these parameters may cause permanent damage.

#### **Product Description**

The ECP052D is a high dynamic range driver amplifier in a low-cost surface mount package. The InGaP/GaAs HBT is able to achieve high performance for various narrowband-tuned application circuits with up to +44 dBm OIP3 and +28.5 dBm of compressed 1dB power. It is housed in an industry standard 16-pin 4x4mm QFN SMT package. All devices are 100% RF and DC tested.

The ECP052D is targeted for use as a driver amplifier in wireless infrastructure where high linearity and medium power is required. An internal active bias allows the ECP052D to maintain high linearity over temperature and operate directly off a single +5V supply. This combination makes the device an excellent candidate for transceiver line cards in current and next generation multi-carrier 3G base stations.

#### **Functional Diagram**



Function	Pin No.
Vref	1
RF Input	3
RF Output	10, 11
Vbias	16
GND	Backside Paddle
N/C or GND	2, 4-9, 12-15

### Ordering Information

Part No.	Description
ECP052D	<sup>1</sup> / <sub>2</sub> Watt InGaP HBT Amplifier (lead-tin 16p 4mm Pkg.)
ECP052D-PCB900	900 MHz Evaluation Board

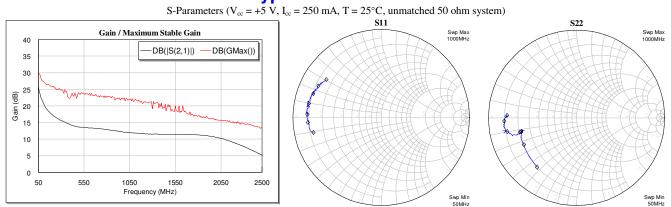
Specifications and information are subject to change without notice

**ECP052D** <sup>1/2</sup> Watt, High Linearity InGaP HBT Amplifier

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**Product Information** 

#### **Typical Device Data**



Notes:

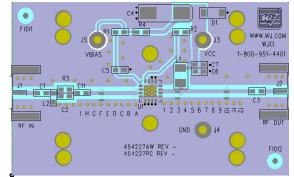
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The gain for the unmatched device in 50 ohm system is shown as the trace in black color. For a tuned circuit for a particular frequency, it is expected that actual gain will be higher, up to the maximum stable gain. The maximum stable gain is shown in the dashed red line. The return loss plots are shown from 50 - 1000 MHz, with markers placed at .05, 0.1 and 0.2 - 1 GHz in 0.2 GHz increments.

Poromotore (V - 15	$V I = 250 m \Lambda$	T - 25°C	unmatched 50 ohm system	calibrated to davias lands)	`
5-Parameters ( $v_{cc} = +3$ )	$v_{1} = 230 \text{ mA}$	1 = 23 C	unmatched 50 onin system	, calibrated to device leads	)

	5 I didilleters	$(v_{cc} = 15, v, I_{cc})$	= 250 m/t, 1 =	25 C, unmater	ied 50 onni syst	enii, canoratea t	o device ieuda)	
Freq (MHz)	S11 (dB)	S11 (ang)	S21 (dB)	S21 (ang)	S12 (dB)	S12 (ang)	S22 (dB)	S22 (ang)
50	-2.08	-167.47	25.81	121.88	-34.39	20.06	-2.85	-128.57
100	-1.60	-176.25	21.21	119.02	-33.70	10.30	-3.46	-152.91
200	-1.55	177.39	17.43	119.68	-34.57	-0.55	-3.77	-165.97
400	-1.57	168.97	14.31	113.15	-35.33	-4.58	-3.57	-165.83
600	-1.76	160.42	13.39	106.07	-33.51	-4.12	-1.91	-168.71
800	-1.97	153.20	12.83	91.91	-33.13	-16.00	-1.70	-177.38
1000	-2.43	145.24	12.08	78.04	-30.97	-28.08	-2.05	177.99
1200	-3.12	137.49	11.67	64.05	-30.23	-36.11	-2.30	175.47
1400	-4.43	127.55	11.46	48.41	-30.25	-46.25	-2.36	174.66
1600	-7.08	115.61	11.47	30.39	-29.61	-62.25	-2.41	173.61
1800	-14.24	109.36	11.30	7.39	-28.18	-82.41	-2.06	171.18
2000	-16.59	-142.19	10.56	-17.73	-28.42	-109.55	-1.64	168.93
2200	-7.06	-146.15	8.89	-43.22	-29.33	-134.21	-1.22	162.93
2400	-3.67	-163.93	6.53	-65.55	-30.99	-158.32	-1.18	155.95
2600	-2.10	179.98	3.89	-83.84	-32.78	179.11	-1.43	149.66
2800	-1.47	166.40	1.31	-98.81	-36.21	169.00	-1.39	144.07
3000	-1.06	153.09	-1.27	-112.21	-36.60	140.50	-1.60	138.31

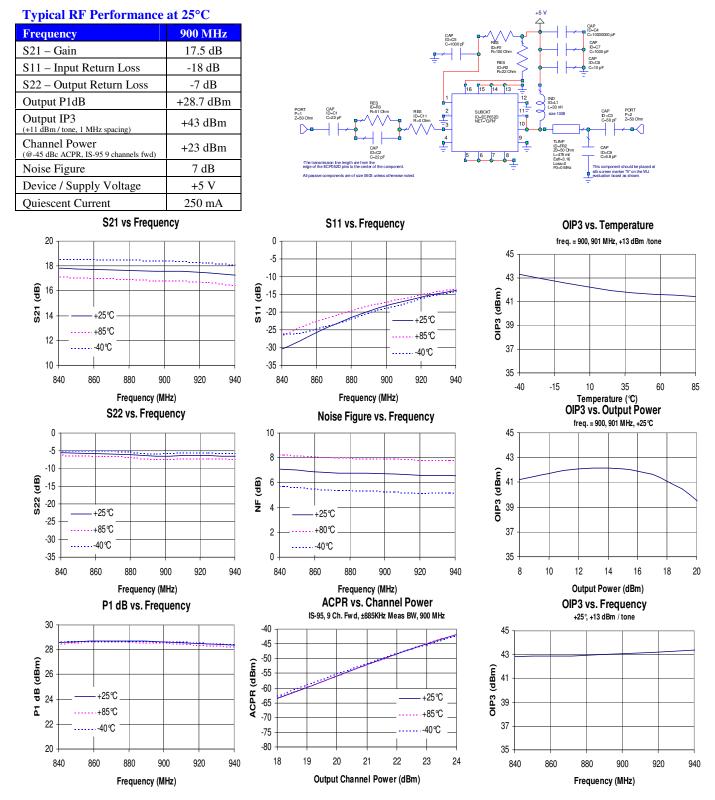
#### **Application Circuit PC Board Layout**



Circuit Board Material: .014" Getek, 4 - layer, 1 oz copper, Microstrip line details: width = .026", spacing = .026" The silk screen markers 'A', 'B', 'C', etc. and '1', '2', '3', etc. are used as placemarkers for the input and output tuning Shunt capacitors – C8, C9 and C10. The markers and vias are spaced in .050" increments.

**Product Information** 

#### 900 MHz Application Circuit (ECP052D-PCB900)



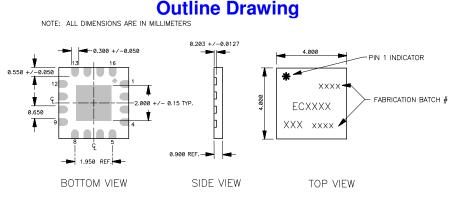


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**Product Information** 

#### ECP052D (16-pin 4x4mm Package) Mechanical Information

This package may contain lead-bearing materials. The plating material on the leads is SnPb.



## Land Pattern 0.25mm DIA. THERMAL GROUND VIA HOLE VIAS ARE PLACEI ON A 0.65mm GRID. VIAS ARE TO BE CONNECTED TO TOP, BOTTOM, AND INTERNAL GROUND PLANES IN ORDER TO MAXIMIZE HEAT DISSIPATION. FOR .031" THK FR4 MATERIA VIA BARREL PLATING TO BE MIN. 0.0014 THICK. VIAS TO BE PLUGGED WITH EITHER CONDUCTIVE OR NON-CONDUCTIV EPOXY TO PREVENT SOLDER. DRAINS THROUGH VIA IN BEELOW DROCEOE

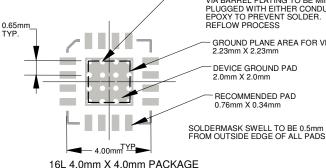
**BEELOW PROCESS** 

DEVICE GROUND PAD 2.0mm X 2.0mm

RECOMMENDED PAD

0.76mm X 0.34mm

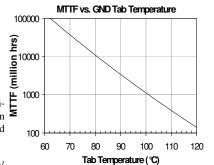
GROUND PLANE AREA FOR VIAS 2.23mm X 2.23mm



#### **Thermal Specifications**

Parameter	Rating
Operating Case Temperature	-40 to +85° C
Thermal Resistance, Rth <sup>(1)</sup>	62° C / W
Junction Temperature, Tjc <sup>(2)</sup>	162° C
Notes:	

- 1. The thermal resistance is referenced from the junctionto-case at a case temperature of 85° C. Tjc is a function of the voltage at pins 10 and 11 and the current applied to pins 10, 11, and 16 and can be calculated by: Tjc = Tcase + Rth \* Vcc \* Icc
- 2. This corresponds to the typical biasing condition of +5V, 250 mA at an 85° C case temperature. A minimum MTTF of 1 million hours is achieved for junction temperatures below 247° C.



#### **Product Marking**

The component will be marked with an "ECP052D" designator with an alphanumeric lot code on the top surface of the package.

Tape and reel specifications for this part are located on the website in the "Application Notes" section.

#### ESD / MSL Information



ESD Rating:	Class 1B
Value:	Passes between 500 and 1000V
Test:	Human Body Model (HBM)
Standard:	JEDEC Standard JESD22-A114

MSL Rating: Level 3 at +235° C convection reflow Standard: JEDEC Standard J-STD-020

#### **Mounting Config. Notes**

- A heatsink underneath the area of the PCB for the mounted 1. device is strictly required for proper thermal operation.
- Damage to the device can occur without the use of one. Ground / thermal vias are critical for the proper performance of this device. Vias should use a .35mm (#80 / .0135") diameter drill and have a final plated thru diameter of .25 mm (.010").
- Add as much copper as possible to inner and outer layers near the part to ensure optimal thermal performance. 3.
- Mounting screws can be added near the part to fasten the 4 board to a heatsink. Ensure that the ground / thermal via region contacts the heatsink.
- 5. Do not put solder mask on the backside of the PC board in the region where the board contacts the heatsink.
- 6. RF trace width depends upon the PC board material and construction. 7. Use 1 oz. Copper minimum.
- All dimensions are in millimeters (inches). Angles are in degrees.